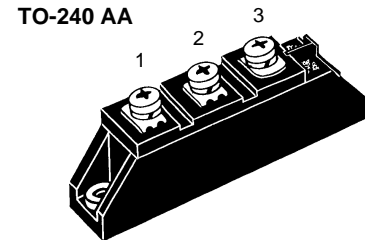
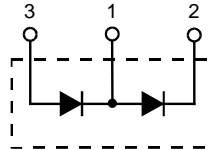


Diode Modules

$I_{FRMS} = 2 \times 60 \text{ A}$
 $I_{FAVM} = 2 \times 36 \text{ A}$
 $V_{RRM} = 800-1800 \text{ V}$

V_{RSM}	V_{RRM}	Type
V	V	
900	800	MDD 26-08N1 B
1300	1200	MDD 26-12N1 B
1500	1400	MDD 26-14N1 B
1700	1600	MDD 26-16N1 B
1900	1800	MDD 26-18N1 B



Symbol	Test Conditions	Maximum Ratings
I_{FRMS}	$T_{VJ} = T_{VJM}$	60 A
I_{FAVM}	$T_C = 100^\circ\text{C}; 180^\circ \text{ sine}$	36 A
I_{FSM}	$T_{VJ} = 45^\circ\text{C}; V_R = 0$	t = 10 ms (50 Hz), sine 650 A
		t = 8.3 ms (60 Hz), sine 760 A
	$T_{VJ} = T_{VJM}; V_R = 0$	t = 10 ms (50 Hz), sine 580 A
		t = 8.3 ms (60 Hz), sine 630 A
$\int i^2 dt$	$T_{VJ} = 45^\circ\text{C}; V_R = 0$	t = 10 ms (50 Hz), sine 2100 A ² s
		t = 8.3 ms (60 Hz), sine 2400 A ² s
	$T_{VJ} = T_{VJM}; V_R = 0$	t = 10 ms (50 Hz), sine 1700 A ² s
		t = 8.3 ms (60 Hz), sine 1900 A ² s
T_{VJ}		-40...+150 °C
T_{VJM}		150 °C
T_{stg}		-40...+125 °C
V_{ISOL}	50/60 Hz, RMS t = 1 min	3000 V~
	$I_{ISOL} \leq 1 \text{ mA}$ t = 1 s	3600 V~
M_d	Mounting torque (M5)	2.5-4/22-35 Nm/lb.in.
	Terminal connection torque (M5)	2.5-4/22-35 Nm/lb.in.
Weight	Typical including screws	90 g

Features

- International standard package JEDEC TO-240 AA
- Direct copper bonded Al₂O₃ -ceramic base plate
- Planar passivated chips
- Isolation voltage 3600 V~
- UL registered, E 72873

Applications

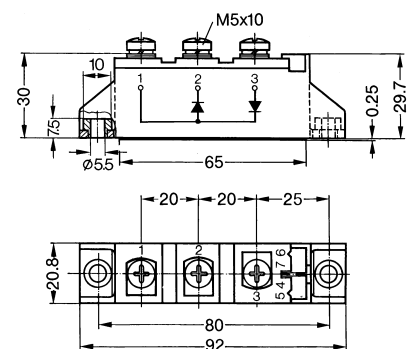
- Supplies for DC power equipment
- DC supply for PWM inverter
- Field supply for DC motors
- Battery DC power supplies

Advantages

- Space and weight savings
- Simple mounting
- Improved temperature and power cycling
- Reduced protection circuits

Symbol	Test Conditions	Characteristic Values
I_R	$T_{VJ} = T_{VJM}; V_R = V_{RRM}$	10 mA
V_F	$I_F = 80 \text{ A}; T_{VJ} = 25^\circ\text{C}$	1.38 V
V_{T0}	For power-loss calculations only	0.8 V
r_T	$T_{VJ} = T_{VJM}$	6.1 mΩ
Q_S	$T_{VJ} = 125^\circ\text{C}; I_F = 25 \text{ A}, -di/dt = 0.6 \text{ A}/\mu\text{s}$	50 μC
I_{RM}		6 A
R_{thJC}	per diode; DC current per module	1.0 K/W
		0.5 K/W
R_{thJK}	per diode; DC current per module	1.2 K/W
		0.6 K/W
d_s	Creepage distance on surface	12.7 mm
d_A	Strike distance through air	9.6 mm
a	Maximum allowable acceleration	50 m/s ²

Dimensions in mm (1 mm = 0.0394")



Data according to IEC 60747 and refer to a single diode unless otherwise stated. IXYS reserves the right to change limits, test conditions and dimensions

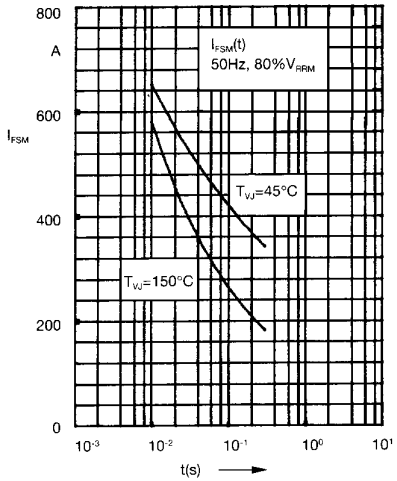


Fig. 1 Surge overload current
 I_{FSM} : Crest value, t : duration

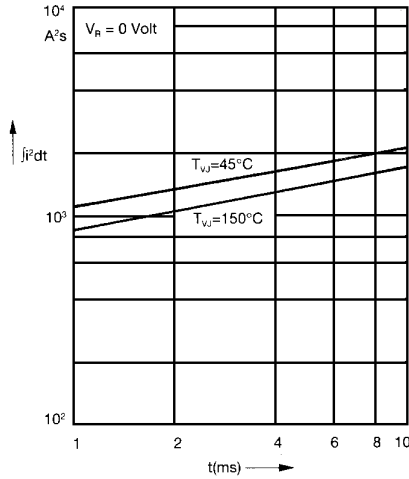


Fig. 2 $\int i^2 dt$ versus time (1-10 ms)

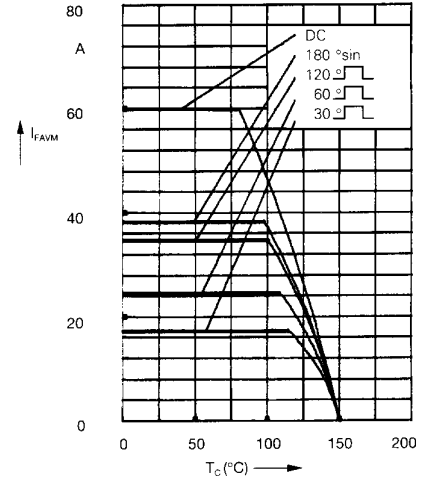


Fig. 2a Maximum forward current at case temperature

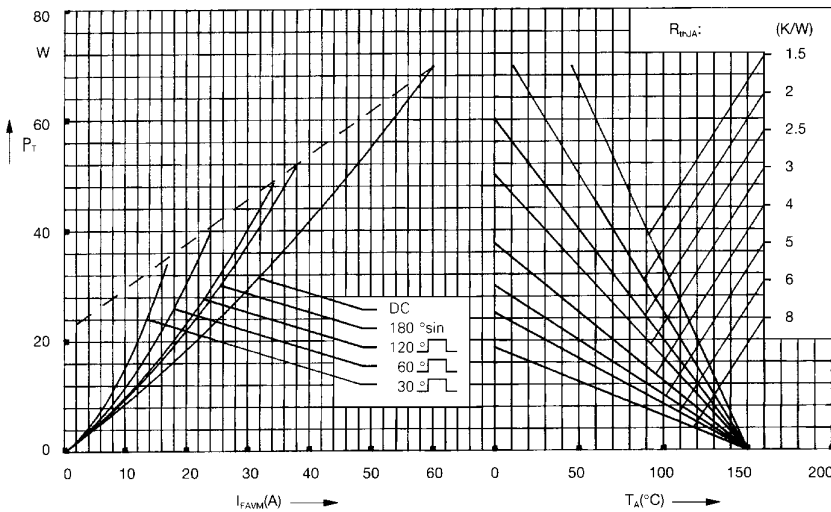


Fig. 3 Power dissipation versus forward current and ambient temperature (per diode)

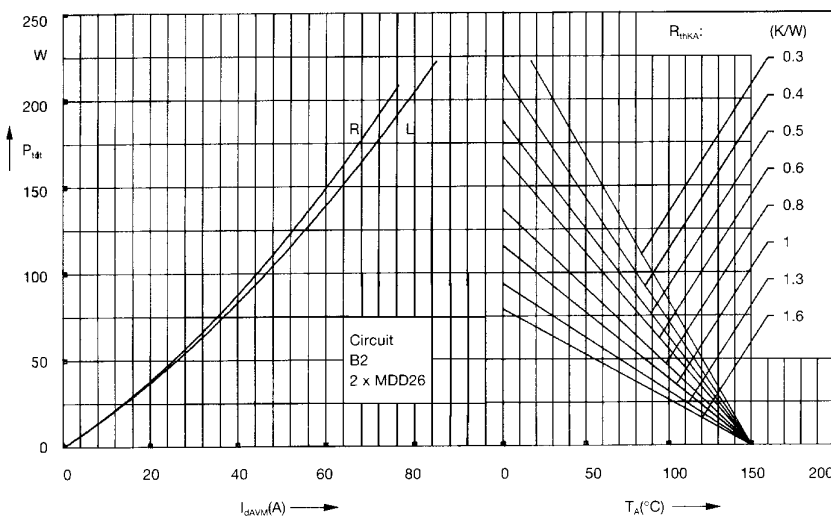


Fig. 4 Single phase rectifier bridge:
 Power dissipation versus direct output current and ambient temperature
 R = resistive load
 L = inductive load

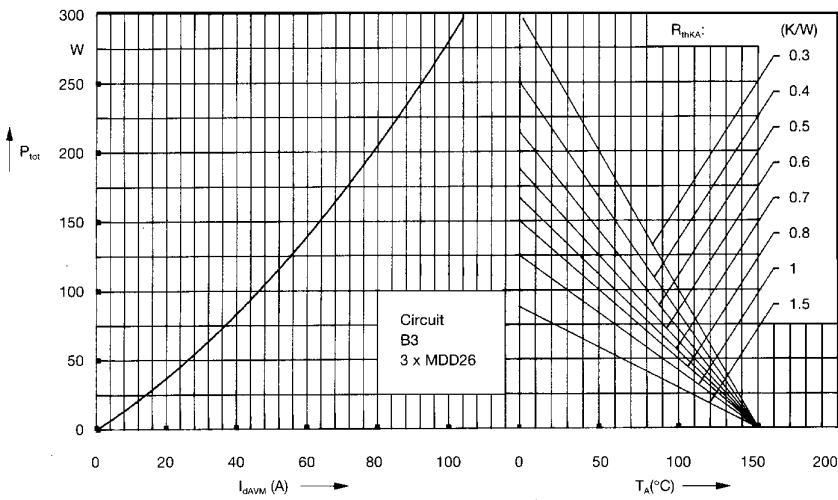


Fig. 5 Three phase rectifier bridge: Power dissipation versus direct output current and ambient temperature

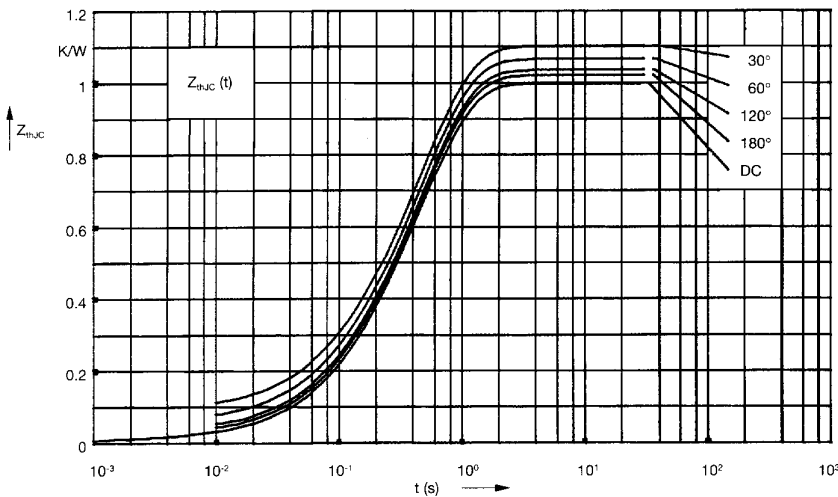


Fig. 6 Transient thermal impedance junction to case (per diode)

R_{thJC} for various conduction angles d:

d	R_{thJC} (K/W)
DC	1.00
180°	1.02
120°	1.04
60°	1.07
30°	1.10

Constants for Z_{thJC} calculation:

i	R_{thi} (K/W)	t_i (s)
1	0.01	0.0012
2	0.03	0.095
3	0.96	0.455

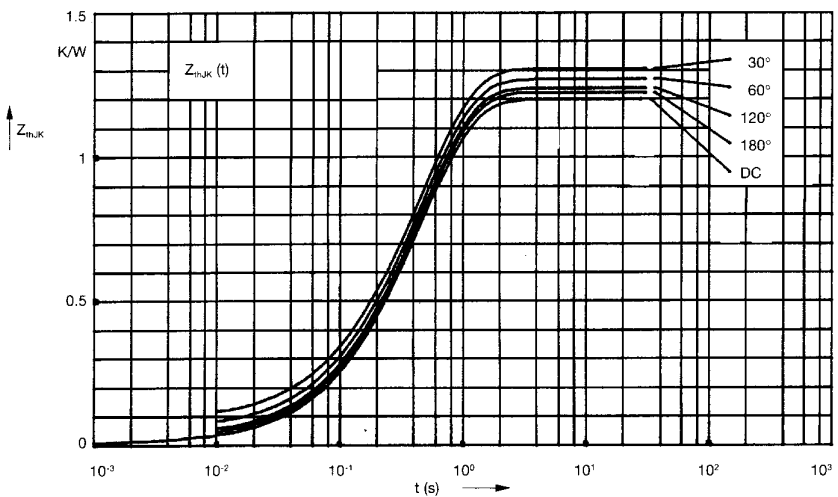


Fig. 7 Transient thermal impedance junction to heatsink (per diode)

R_{thJK} for various conduction angles d:

d	R_{thJK} (K/W)
DC	1.20
180°	1.22
120°	1.24
60°	1.27
30°	1.30

Constants for Z_{thJK} calculation:

i	R_{thi} (K/W)	t_i (s)
1	0.01	0.0012
2	0.03	0.095
3	0.96	0.455
4	0.2	0.495